

## DL-4039-011

# Index Guided AlGaInP Laser Diode

#### Overview

DL-4039-011 is 675 nm (Typ.) index guided AlGaInP laser diode with low threshold current and 10 mW high power.

The low threshold current and short wavelength are achieved by the use of a strained multiple quantum well active layer. DL-4039-011 is suitable for applications such as bar-code scanners, laser pointers and other optical information systems.

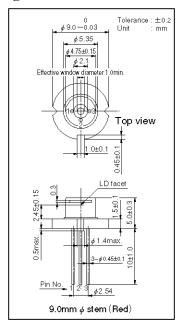
#### Features

Short wavelength : 675 nm (Typ.)
Output power : 10 mW CW
Low threshold current : Ith = 40 mA (Typ.)
High operating temperature : 50°C at 10 mW

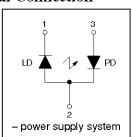
### **Absolute Maximum Ratings at Tc=25℃**

Parameter		Symbol	Ratings	Unit	
Light Output		Po	10	mW	
Reverse Voltage	Laser PIN	VR	2 30	V	
Operating Temperature		Topr	-10 to +50	$^{\circ}\!\mathbb{C}$	
Storage Temperature		Tstg	-40 to +85	$^{\circ}\mathbb{C}$	

## **Package Dimensions**



#### **Electrical Connection**



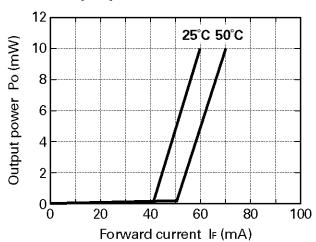
## Electrical and Optical Characteristics at Tc=25°C

Para	meter	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshol	d Current	Ith	CW	_	40	70	mA
Operatin	g Current	Iop	Po=10mW	_	60	90	mA
Operatin	g Voltage	Vop	Po=10mW	_	2.3	2.6	V
Lasing W	avelength	λp	Po=10mW	665	675	685	nm
Beam 💥 )	Perpendicular	$\theta \perp$	Po=10mW	25	30	40	deg.
Divergence	Parallel	θ //	Po=10mW	6	8	10	deg.
Off Axis	Perpendicular	$\Delta \theta \perp$	_	_	_	±3	deg.
Angle	Parallel	$\Delta  heta$ //	_	_	_	±3	deg.
Differentia	l Efficiency	dPo/dIop	_	0.2	0.5	_	mW/mA
Monitoring C	output Current	Im	Po=10mW	0.05	0.15	0.4	mA
Astign	natism	As	Po=10mW	_	8	_	μm

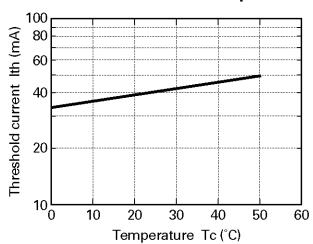
<sup>\* )</sup> Full angle at half maximum note: The above product specifications are subject to change without notice.

#### Characteristics

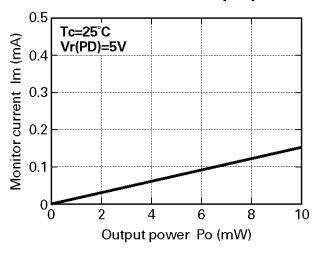




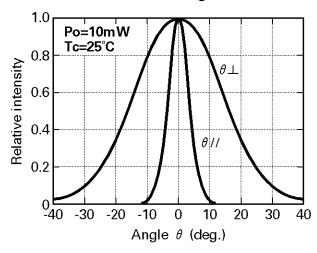
## Threshold current vs. Temperature



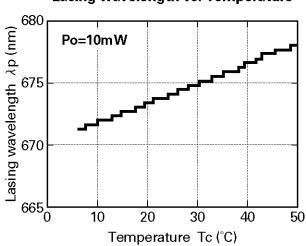
## Monitor current vs. Output power



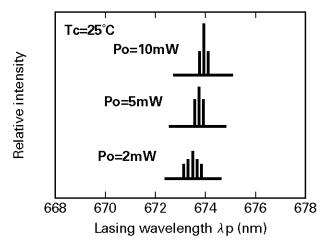
## Beam divergence



## Lasing wavelength vs. Temperature



## Output power vs. Lasing wavelength





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# Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by; Tottori SANYO Electric Co., Ltd.

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